
Level Shifter Design Example

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General Description

Semiconductor technology advancements, proliferating I/O standards, legacy support requirements, and the relentless drive to design and manufacture lower power systems require most applications to utilize a mix of power supply and I/O drive voltages. Today's lower power devices have to work in this eco-system with the older, higher voltage devices, requiring solutions that interface with the multiple voltages that are in widespread use today.

Level-translator integrated circuits (ICs) are a common solution, but they do not necessarily provide the flexibility to support multiple simultaneous translations to different voltages or I/O interface standard. Level-translator ICs can add unnecessary cost if the system already contains an FPGA on board. This level shifter design example provides a low-cost, low-power, highly flexible solution that utilizes Microsemi IGLOO[®] low-power FPGAs.

Design Description

All Microsemi IGLOO and ProASIC[®]3 low-power FPGAs support multiple voltage options for I/O banks. The VCCI of each bank determines the voltage level of its I/Os. Within the IGLOO series of FPGAs, I/O voltages are available from 1.2 V up to 3.3 V, including several flexible wide range I/O voltage options.

This design example is based on the IGLOO starter kit board (part number AGL-DEV-KIT-SCS), although the design and instructions can be easily adapted to work with any of the Microsemi IGLOO or ProASIC3 boards. A full list of available boards can be found on the Microsemi website (www.microsemi.com).

Design files can be downloaded from the Microsemi website:
http://soc.microsemi.com/download/rsc/?f=LevelShifter_DF.

Figure 1 shows the provision for selecting I/O bank VCCI voltages on the IGLOO starter kit by using jumpers. Bank1 can use an I/O voltage of 3.3 V or 1.5 V. Bank2 can use an I/O voltage of 2.5 V or 1.5 V.

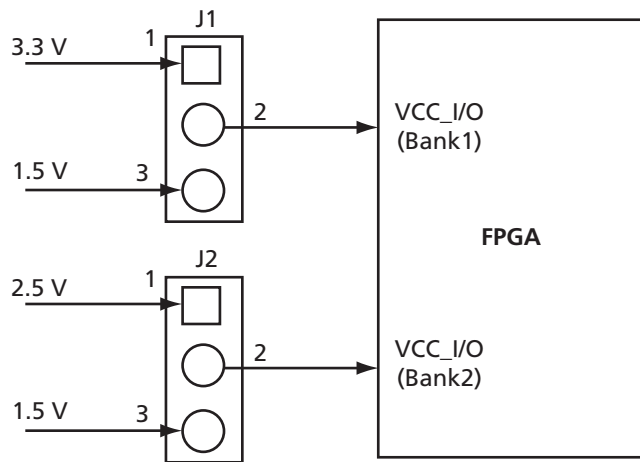


Figure 1 • Jumper Setting

Top-Level Block Diagram

The logic in this design example is the straightforward passing of data from inputs on one voltage bank to outputs on another voltage bank (Figure 2).

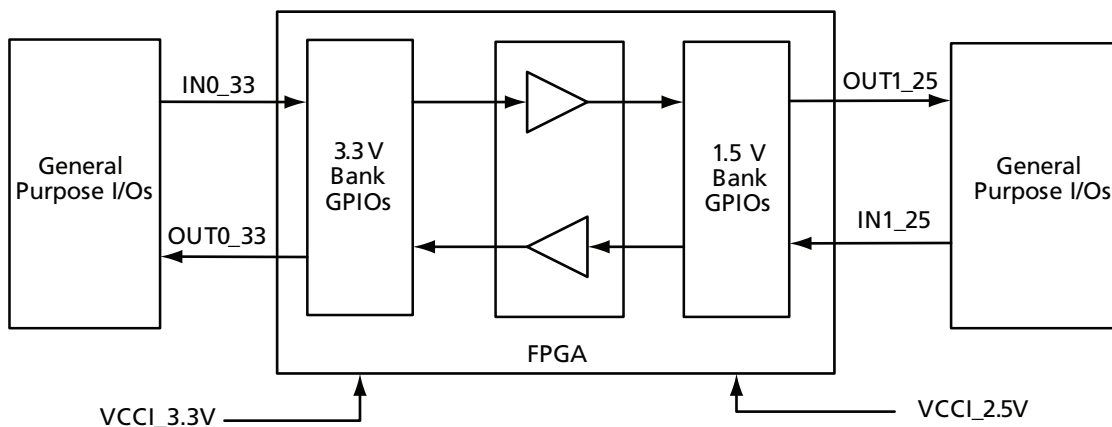


Figure 2 • System Block Diagram

The design does not consume any other logic than the routing resources and I/Os.

Interface Description

Table 1 describes the interconnections between the ports and the I/Os.

Table 1 • Signal Description

Port	Direction	Description
IN1_25	I	2.5 V input connected to Bank1
IN0_33	I	3.3 V input connected to Bank0
OUT1_25	O	2.5 V output connected to Bank1
OUT0_33	O	3.3 V output connected to Bank0

Utilization Details

For testing purposes, this design was created for the M1AGL600V2-484FBGA device. Table 2 describes the utilization details after place-and-route.

Table 2 • Utilization Details

Resource	Utilized	Total	Percentage
Core	0	13,824	0.00 %
I/Os	4	235	1.70%
Differential I/Os	0	60	0.00%
GLOBAL (chip + quadrant)	0	18	0.00 %
PLL	0	1	0.00 %
RAM/FIFO	0	24	0.00 %
Low Static ICC	0	1	0.00 %
FlashROM	0	1	0.00 %
User JTAG	0	1	0.00 %

Testing Scheme

This design was tested and verified on the M1AGL600V2 development kit. In this board, the VCCI for Bank0 is 3.3 V and 2.5 V for Bank1.

For verifying the functionality of the IP, an external clock source of 2.5 V amplitude was connected to one of the pins of Bank1. The logic within the FPGA connects this pin to one of the pins of Bank0. Table 3 shows the connectivity details.

Table 3 • Details of 2.5 V to 3.3 V Conversion

Signal Name	Direction	Bank / VCCI	FPGA Pin Number	Board Reference	Voltage Measured
IN1_25	Input	Bank1 / 2.5 V	H16	P2 Pin No.4	2.5 V
OUT0_33	Output	Bank0 / 3.3 V	D5	P1 Pin No. 4	3.3 V

The voltage level translation, from 2.5 V to 3.3 V, is shown in Figure 3 on page 4.

Timing Diagrams

Figure 3 shows the timing diagram for the 2.5 V to 3.3 V translation.

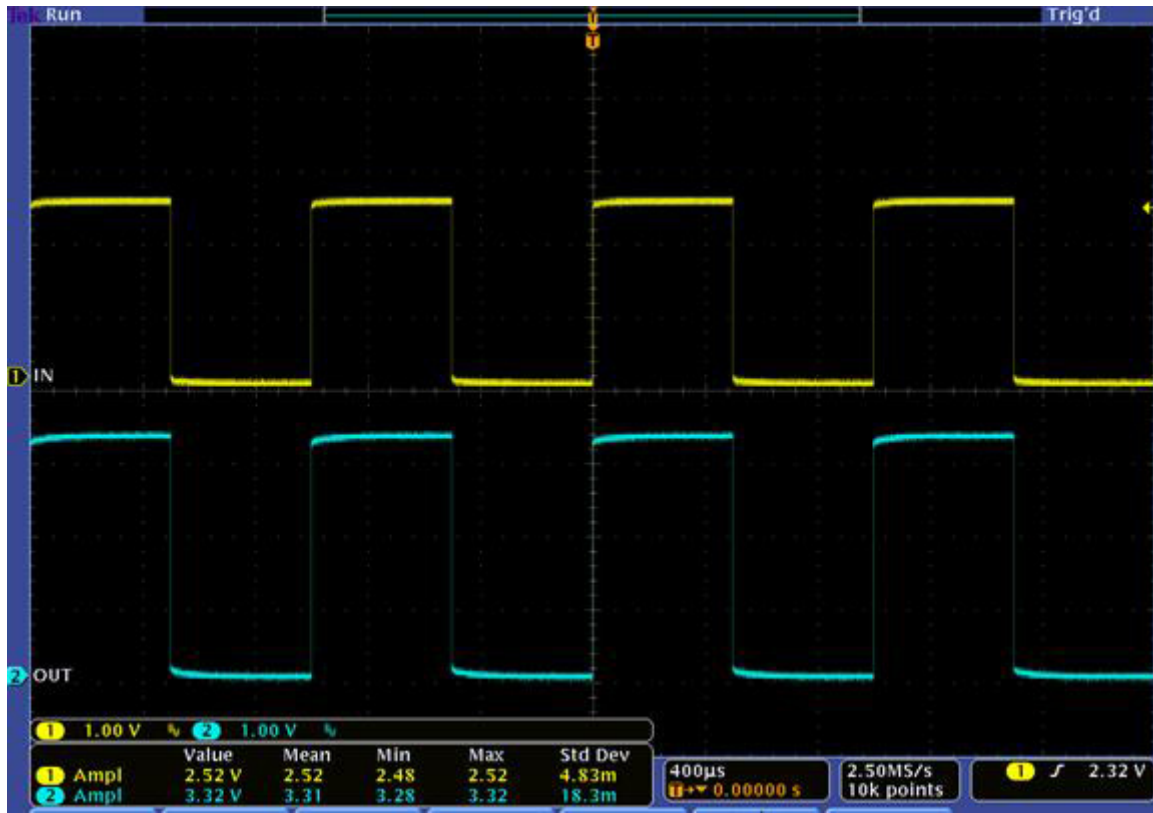


Figure 3 • Translating from 2.5 V to 3.3 V

Another sets of pins were used for the 3.3 V to 2.5 V conversion. The connectivity details are shown in Table 4.

Table 4 • Details of 3.3 V to 2.5 V Conversion

Signal Name	Direction	Bank / VCCI	FPGA Pin Number	Board Reference	Voltage Measured
IN0_33	Input	Bank0 / 3.3 V	D10	P1 Pin No. 6	3.3 V
OUT1_25	Output	Bank1 / 2.5 V	J16	P2 Pin No. 35	2.5 V

Figure 4 shows the resulting waveform.

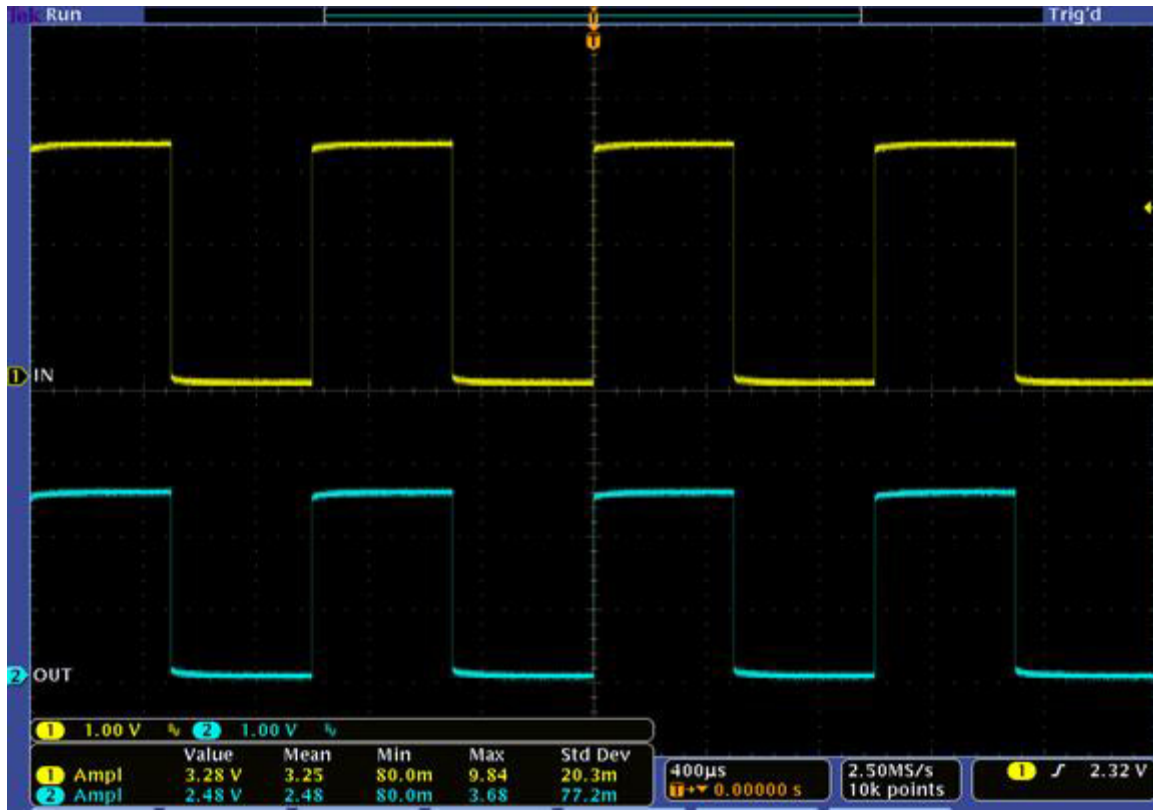


Figure 4 • Translating from 3.3 V to 2.5 V

List of Changes

The following table shows important changes made in this document for each revision.

Date	Changes	Page
Revision 2 (June 2015)	Non-technical Updates.	NA
Revision 1 (April 2009)	Initial Release.	NA

Note: *The revision number is located in the part number after the hyphen. The part number is displayed at the bottom of the last page of the document. The digits following the slash indicate the month and year of publication.



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